

S11	12172230	US- "5,607,341" US- "5,836,807" US- "6,354,928" B1 US- "6,390, 901" B1 US- "6,390,905" B1 US- "6,394,882" B1 US- "6,435,948" B1 US- "6,436,828" B1 US- "6,443, 821" B1 US- "6,447,368" B1 US- "6,506,105" B1 US- "6,558,232" B1 US- "6,592,434" B1 US- "6, 612,903" US- "6,623,343" US- "6, 659,850" US- "6,719,615" B14606151	US-PGPUB; USPAT; USOCR	OR	OFF	2005/04/04 17:10
S12	12172230	US- "5,607,341" US- "5,836,807" US- "6,354,928" B1 US- "6,390, 901" B1 US- "6,390,905" B1 US- "6,394,882" B1 US- "6,435,948" B1 US- "6,436,828" B1 US- "6,443, 821" B1 US- "6,447,368" B1 US- "6,506,105" B1 US- "6,558,232" B1 US- "6,592,434" B1 US- "6, 612,903" US- "6,623,343" US- "6, 659,850" US- "6,719,615" B1	US-PGPUB; USPAT; USOCR	OR	OFF	2005/04/04 17:11
S13	7436193	US- "5,607,341" US- "5,836,807" US- "6,354,928" B1 US- "6,390, 901" B1 US- "6,390,905" B1 US- "6,394,882" B1 US- "6,435,948" B1 US- "6,436,828" B1 US- "6,443, 821" B1 US- "6,447,368" B1 US- "6,506,105" B1 US- "6,558,232" B1 US- "6,592,434" B1 US- "6, 612,903" US- "6,623,343" US- "6, 659,850" US- "6,719,615" B1	USPAT	OR	OFF.	2005/04/04 17:11
S14	18	"4606151"	USPAT	OR	OFF	2005/04/04 17:11
S15	17	(US- "5,607,341" US- "5,836,807" US- "6,354,928" B1 US- "6,390, 901" B1 US- "6,390,905" B1 US- "6,394,882" B1 US- "6,435,948" B1 US- "6,436,828" B1 US- "6,443, 821" B1 US- "6,447,368" B1 US- "6,506,105" B1 US- "6,558,232" B1 US- "6,592,434" B1 US- "6, 612,903" US- "6,623,343" US- "6, 659,850" US- "6,719,615" B1).pn.	USPAT	OR	OFF	2005/04/04 17:11
S16	1	"4606151".pn.	USPAT	OR	OFF	2005/04/04 17:12
S17	18	S15 S16	USPAT	OR	OFF	2005/04/04 17:18
S18	7434	"force gradient" "shear force"	USPAT	OR	OFF	2005/04/04 17:18
S19	593	S18 and (polish\$3 planariz\$6)	USPAT	OR	OFF	2005/04/04 17:19
S20	125	S19 and ((first and second)or (subsequent)) with (wafer substrate semiconductor)	USPAT	OR	OFF	2005/04/04 17:20